DRIVING CIRCUIT CONFIGURED IN A THREE-PHASE INVERTER AND DRIVING METHOD THEREOF

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FIELD OF THE INVENTION

The present invention relates generally to a driving circuit, and more particularly, to a driving circuit and method for three-phase cold cathode fluorescent lamps (CCFL).

BACKGROUND OF THE INVENTION

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CCFL has been widely used for the backlight of display, especially the liquid crystal display (LCD), due to its advantages of power saving, low power dissipation, decreased heat generation, long life time, small size, light weight, high illumination, high color rendering, and moderate lamp temperature after long-term used. Conventionally, it is sufficient of only one CCFL for a display, because of the small size of the display. As the progress in technology, however, the display becomes larger and therefore the amount of the CCFLs served as the light source has to be increased. Thus, there is a need for a driving circuit capable of

driving several CCFLs.

A driving circuit proposed by U.S. Pat. No. 6,396,722 issued to Lin comprises four MOS transistors and one transformer to be constituted a full-bridge circuit to drive CCFL. However, only one CCFL could be driven by this circuit, and several such individual full-bridge circuits are needed if several CCFLs to be driven. Further, due to the fact that MOS transistor and transformer are all costly elements, the more ones being used, the cost is higher.

Therefore, it is desired a driving circuit capable of driving several CCFLs with a reduced cost.

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SUMMARY OF THE INVENTION

It is an object of the present invention to disclose a driving circuit and method that employs a three-phase inverter configuration for driving a plurality of CCFLs.

It is another object of the present invention to propose a driving circuit and method capable of driving a plurality of CCFLs with reduced cost.

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In a driving circuit configured in a three-phase inverter, according to the present invention, it is comprised a first switch assembly including a first high-side switch connected between an input voltage and a first node, and a first low-side switch connected between the first node and a reference voltage, a second switch assembly including a second high-side switch connected between the input voltage and a second node, and a second low-side switch connected between the second node and reference voltage, a third switch assembly including a third high-side switch connected between the input voltage and a third node, and a third low-side switch connected between the third node and reference voltage, and a three-phase transformer with three terminals of its primary side connected to the three nodes, respectively, and three terminals of its secondary side connected to three loadings, respectively. The switches are switched to generate a first AC voltage between the first and second nodes, a second AC voltage between the second and third nodes, and a third AC voltage between the third and first nodes, respectively. The three AC voltages are further transformed to three AC currents by the three-phase transformer to provide for the three loadings, and each of them includes at least one CCFL to be driven by the AC current flowing therethrough.

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BRIEF DESCRIPTION OF DRAWINGS

These and other objects, features and advantages of the present invention will become apparent to those skilled in the art upon consideration of the following description of the preferred embodiments of the present invention taken in conjunction with the accompanying drawings, in which:

Fig. 1 shows a driving circuit configured in a three-phase inverter according to the present invention;

Fig. 2 shows a timing diagram of the waveforms of the voltages between the nodes A and B, B and C, and C and A, respectively, of the circuit shown in Fig. 1;

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- Fig. 3 shows a timing diagram of the waveforms of the currents flowing through three CCFLs of the circuit shown in Fig. 1;
- Fig. 4 shows another embodiment driving circuit according to the present invention;
 - Fig. 5 shows a further embodiment driving circuit according to the present invention; and

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Fig. 6 shows an application of the driving circuit according to the present invention.

DETAILED DESCRIPTION OF THE INVENTION

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Fig. 1 shows a preferred embodiment of a driving circuit 10 configured in a three-phase inverter, which comprises a switch assembly 12 connected between an input voltage Vin and ground GND1, and including a high-side NMOS transistor 122 connected between the input voltage Vin and node A, and a low-side NMOS transistor 124 connected between the node A and ground GND1. Likewise, another switch assembly 14 is connected between the input voltage Vin and ground GND1, and includes a high-side NMOS transistor 142 connected between the input voltage Vin and node B, and a low-side NMOS transistor 144 connected between the node B and ground GND1, and a third switch assembly 16 is connected between the input voltage Vin and ground GND1, and includes a high-side NMOS transistor 162 connected between the input voltage Vin and node C, and a low-side NMOS transistor 164 connected between the node C and ground GND1. In addition, six diodes D₁-D₆ are connected in parallel to the six NMOS transistors 122-164, respectively, and a three-phase transformer 18 including two transformers TX1 and TX2 connected in series has its primary side connected to the nodes A, B and C, and its secondary side connected with three CCFLs 20, 22 and 24 between thereto and ground GND2. All the NMOS transistors 122, 124, 142, 144, 162, and 164 are provided for switches each under the control of one of the signals S₁, S₂, S₃, S₄, S₅, and S₆.

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Fig. 2 shows waveforms 26, 28, and 30 for the voltages V_{AB} between the nodes A and B, V_{BC} between the nodes B and C, as well as V_{CA} between the nodes C and A, respectively, of the circuit shown in Fig. 1, where the phases of these three AC voltages are displaced from each other by 120 degrees. conjunction of referring to Fig. 1, in the operation of the circuit 10, the transistors 122, 144, and 162 are turned on to conduct currents I_{AB} , I_{CB} and I_{CA} during the time period of 0 to t_1 , the transistors 122, 144, and 164 are turned on to conduct currents IAB, ICB and IAC during the time period of t1 to t2, the transistors 122, 142, and 164 are turned on to conduct currents IAB, IBC and IAC during the time period of t₂ to t₃, the transistors 124, 142, and 164 are turned on to conduct currents IBA, IBC and IAC during the time period of t3 to t4, the transistors 124, 142, and 162 are turned on to conduct currents IBA, IBC and ICA during the time period of t4 to to, and the transistors 124, 144, and 162 are turned on to conduct currents IBA, ICB and ICA during the time period of t5 to t6. As such, the AC voltage VAB between the nodes A and B, the AC voltage V_{BC} between the nodes B and C, and the AC voltage V_{CA} between the nodes C and A are transformed by the three-phase

transformer 18 to AC currents I_1 , I_2 and I_3 to flow through the CCFLs 20, 22 and 24, respectively. From one point of view, systematically, the three AC voltages V_{AB} , V_{BC} and V_{CA} form a three-phase voltage, and the three AC currents I_1 , I_2 and I_3 form a three-phase current, since dependence is presented between the three phases.

From Fig. 2, obviously, each time interval, for example from 0 to t_1 , equals to 1/6 cycle since from 0 to t_6 is a complete cycle, and thus, the voltage waveforms 26, 28 and 30 of this embodiment are displaced from each other by 120 degrees in phase. On the other hand, the waveforms 32, 34 and 36 shown in Fig. 3 represent the AC current waveforms I_1 , I_2 , and I_3 of the circuit 10 shown in Fig. 1. As in the afore-mentioned operation, the phases of the current waveforms 32, 34 and 36 are also displaced from each other by 120 degrees.

A typical three-phase transformer is constituted by three transformers. However, decreasing of one transformer has no effect on the generation of the three-phase current according to the principle of the three-phase circuit. For the purpose of cost reduction, two transformers TX_1 and TX_2 are preferred to be connected in series to constitute the three-phase transformer 18. For comparison, the driving circuit proposed by the '722 patent needs three sets of substantially equivalent full-bridge driving

circuits and as a result, twelve NMOS transistors and three transformers are needed. In contrast, there needs only six NMOS transistors as well as two transformers for the circuit 10 to drive three CCFLs, which is less than the conventional driving circuit by six NMOS transistors as well as one transformer, resulting in dramatic reduction of cost.

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Fig. 4 is a second embodiment of the present invention. The driving circuit 38 hereof is similar to the previous driving circuit 10, except that the three-phase transformer 18 has a Δ - Δ configuration instead, i.e., the three-phase transformer 18 is constituted by three transformers TX₁, TX₂ and TX₃ connected in Δ - Δ configuration. The connection 1804 at the primary side of the transformer TX₁ is connected to the terminal 1806 at the primary side of the transformer TX₂, the other terminal 1808 at the primary side of the transformer TX2 is connected to the terminal 1810 at the primary side of the transformer TX3, the other terminal 1812 at the primary side of the transformer TX₃ is connected to the connection 1802 at the primary side of the transformer TX₁. While the connection 1816 at the secondary side of the transformer TX_1 is connected to the terminal 1818 at the secondary side of the transformer TX2, the other terminal 1820 at the secondary side of the transformer TX2 is connected to the terminal 1822 at the secondary side of the transformer TX3, the other terminal 1824 at the secondary side of the transformer TX3 is connected to the

connection 1814 at the secondary side of the transformer TX₁. Further, the connections 1802, 1806 and 1810 are connected to the nodes A, B and C, respectively, and the connections 1814, 1818 and 1822 are connected to the CCFLs 20, 22 and 24, respectively. This manner, it is obtained the cost reduction of decreasing six NMOS transistors.

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Fig. 5 shows a third embodiment of the present invention. The driving circuit 40 is also similar to the circuit 38, except that the three-phase transformer 18 has a Y-Y connection instead, i.e., the three-phase transformer 18 is constituted by three transformers TX₁, TX₂ and TX₃ connected in Y-Y configuration. The terminals 1802, 1806 and 1810 at the primary sides of the transformers TX₁, TX₂ and TX₃ are connected to the nodes A, B and C, respectively, and the other terminals 1804, 1808 and 1812 of them are connected to ground GND3. While the terminals 1814, 1818 and 1822 at the secondary sides of the transformers TX₁, TX₂ and TX₃ are connected to the CCFLs 20, 22 and 24, respectively, and the other terminals 1816, 1820 and 1824 are connected to ground GND4. It is also obtained in this circuit 40 with the cost reduction of decreasing six NMOS transistors, as for the driving circuit 38.

If more than three CCFLs are to be driven, the CCFLs 202, 222 and 242 of the circuits 10, 38 or 40 could be connected

in parallel with other CCFLs, and Fig. 6 shows an exemplatory circuit 42 for such situations.

While the present invention has been described in conjunction with preferred embodiments thereof, it is evident that many alternatives, modifications and variations will be apparent to those skilled in the art. Accordingly, it is intended to embrace all such alternatives, modifications and variations that fall within the spirit and scope thereof as set forth in the appended claims.